



UAF42

UNIVERSAL ACTIVE FILTER

FEATURES

- VERSATILE— LOW-PASS, HIGH-PASS BAND-PASS, BAND-REJECT
- SIMPLE DESIGN PROCEDURE

DESCRIPTION

The UAF42 is a universal active filter which can be configured for a wide range of low-pass, high-pass, and band-pass filters. It uses a classical state-variable analog architecture with an inverting amplifier and two integrators. The integrators include on-chip 1000pF capacitors trimmed to 0.5%. This solves one of the most difficult problems of active filter design—obtaining tight tolerance, low-loss capacitors.

A DOS-compatible filter design program allows easy implementation of many filter types such as Butterworth, Bessel, and Chebyshev. A fourth, uncommitted FET-input op amp (identical to the other

APPLICATIONS

- TEST EQUIPMENT
- COMMUNICATIONS EQUIPMENT
- MEDICAL INSTRUMENTATION
- DATA ACQUISITION SYSTEMS
- MONOLITHIC REPLACEMENT FOR UAF41

three) can be used to form additional stages, or for special filters such as band-reject and Inverse Chebyshev.

The classical topology of the UAF42 forms a timecontinuous filter, free from the anomalies and switching noise associated with switched-capacitor filter types.

The UAF42 is available in 14-pin plastic DIP and SOL-16 surface-mount packages, specified for the -25° C to $+85^{\circ}$ C temperature range.



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SPECIFICATIONS

ELECTRICAL

At $T_A = +25^{\circ}C$, $V_S = \pm 15V$, unless otherwise noted.

		UAF42AP, AU			
PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
FILTER PERFORMANCE Frequency Range, fn Frequency Accuracy vs Temperature Maximum Q Maximun (Q • Frequency) Product Q vs Temperature Q Repeatability Offset Voltage, Low-Pass Output Resistor Accuracy	$f = 1 \text{kHz}$ $(f_{O} \bullet Q) < 10^{4}$ $(f_{O} \bullet Q) < 10^{5}$ $(f_{O} \bullet Q) < 10^{5}$		0 to 100 0.01 400 500 0.01 0.025 2 0.5	1 ±5 1%	kHz % — kHz %/°C %/°C % mV %
OFFSET VOLTAGE ⁽¹⁾ Input Offset Voltage vs Temperature vs Power Supply INPUT BIAS CURRENT ⁽¹⁾	$V_{\rm S} = \pm 6 \text{ to } \pm 18 \text{V}$	80	±0.5 ±3 96	±5	mV μV/°C dB
Input Offset Current	$V_{CM} = 0V$ $V_{CM} = 0V$		5	50	рА pA
NOISE Input Voltage Noise Noise Density: f = 10Hz f = 10kHz Voltage Noise: BW = 0.1 to 10Hz Input Bias Current Noise Noise Density: f = 10kHz			25 10 2 2		nV/√Hz nV/√Hz μVp-p fA/√Hz
INPUT VOLTAGE RANGE ⁽¹⁾ Common-Mode Input Range Common-Mode Rejection	V _{CM} = ±10V	80	±11.5 96		V dB
INPUT IMPEDANCE ⁽¹⁾ Differential Common-Mode			10 ¹³ 2 10 ¹³ 6		Ω pF Ω pF
OPEN-LOOP GAIN ⁽¹⁾ Open-Loop Voltage Gain	$V_0 = \pm 10V, R_L = 2k\Omega$	90	126		dB
FREQUENCY RESPONSE ⁽¹⁾ Slew Rate Gain-Bandwidth Product Total Harmonic Distortion	G = +1 G = +1, f = 1kHz		10 4 0.0004		V/µs MHz %
OUTPUT ⁽¹⁾ Voltage Output Short Circuit Current	$R_L = 2k\Omega$	±11	±11.5 ±25		V mA
POWER SUPPLY Specified Operating Voltage Operating Voltage Range Current		±6	±15 ±6	±18 ±7	V V mA
TEMPERATURE RANGE Specification Operating Storage Thermal Resistance, θ_{JA}		-25 -25 -40	100	+85 +85 +125	°C °C °C W,Q

* Same as specification for UAF42AP.

NOTES: (1) Specifications apply to uncommitted op amp, A₄. The three op amps forming the filter are identical to A₄ but are tested as a complete filter.

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PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS

Power Supply Voltage±18V	Powe
nput Voltage $\pm V_{s} \pm 0.7V$	Input
Dutput Short Circuit Continuous	Outpu
Derating Temperature:	Opera
Plastic DIP, P; SOIC, U40°C to +85°C	Plas
Storage Temperature:	Stora
Plastic DIP, P; SOIC, U40°C to +125°C	Plas
unction Temperature:	Juncti
Plastic DIP, P; SOIC, U +125°C	Plas
ead Temperature (soldering, 10s) +300°C	Lead

PACKAGE/ORDERING INFORMATION

PRODUCT	PACKAGE	PACKAGE DRAWING NUMBER ⁽¹⁾	TEMPERATURE RANGE
UAF42AP	Plastic 14-pin DIP	010	−25°C to +85°C
UAF42AU	SOL-16	211	−25°C to +85°C

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book.

ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



APPLICATIONS INFORMATION

The UAF42 is a monolithic implementation of the proven state-variable analog filter topology. Pin-compatible with the popular UAF41 Analog Filter, it provides several improvements.

Slew Rate of the UAF42 has been increased to $10V/\mu s$ versus $1.6V/\mu s$ for the UAF41. Frequency • Q product of the UAF42 has been improved, and the useful natural frequency extended by a factor of four to 100 kHz. FET-input op amps on the UAF42 provide very low input bias current. The monolithic construction of the UAF42 provides lower cost and improved reliability.

DESIGN PROGRAM

Application Bulletin AB-035 and a computer-aided design program, available from Burr-Brown, make it easy to design and implement many kinds of active filters. The DOScompatible program guides you through the design process and automatically calculates component values.

Low-pass, high-pass, band-pass and band-reject (notch) filters can be designed. The program supports the three most commonly used all-pole filter types: Butterworth, Chebyshev and Bessel. The less-familiar Inverse Chebyshev is also supported, providing a smooth passband response with ripple in the stop-band.

With each data entry, the program automatically calculates and displays filter performance. This allows a spreadsheetlike "what if" design approach. For example, you can quickly determine, by trial and error, how many poles are required for a desired attenuation in the stopband. Gain/phase plots may be viewed for any response type. The basic building element of the most commonly used filter types is the second-order section. This section provides a complex-conjugate pair of poles. The natural frequency, ω_n , and Q of the pole pair determines the characteristic response of the section. The low-pass transfer function is

$$\frac{V_{O}(s)}{V_{I}(s)} = \frac{A_{LP}\omega_{n}^{2}}{s^{2} + s \omega_{n}/Q + \omega_{n}^{2}}$$
(1)

The high-pass transfer function is

$$\frac{V_{HP}(s)}{V_{I}(s)} = \frac{A_{HP}s^{2}}{s^{2} + s \omega_{n}/Q + \omega_{n}^{2}}$$
(2)

The band-pass transfer function is

$$\frac{V_{BP}(s)}{V_{I}(s)} = \frac{A_{BP}(\omega_{n}/Q) s}{s^{2} + s \omega_{n}/Q + \omega_{n}^{2}}$$
(3)

A band-reject response is obtained by summing the low-pass and high-pass outputs, yielding the transfer function

$$\frac{V_{BR}(s)}{V_{I}(s)} = \frac{A_{BR}(s^{2} + \omega_{n}^{2})}{s^{2} + s \omega_{n}/Q + \omega_{n}^{2}}$$
(4)

The most commonly used filter types are formed with one or more cascaded second-order sections. Each section is designed for ω_n and Q according to the filter type (Butterworth, Bessel, Chebyshev, etc.) and cutoff frequency. While tabulated data can be found in virtually any filter design text, the design program eliminates this tedious procedure.

Second-order sections may be non-inverting (Figure 1) or inverting (Figure 2). Design equations for these two basic configurations are shown for reference. The design program solves these equations, providing complete results, including component values.





FIGURE 1. Non-Inverting Pole-Pair.





FIGURE 2. Inverting Pole-Pair.



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
UAF42AP	ACTIVE	PDIP	Ν	14	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UAF42AP-1	OBSOLETE	PDIP	Ν	14		TBD	Call TI	Call TI
UAF42APG4	ACTIVE	PDIP	Ν	14	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UAF42AU	ACTIVE	SOIC	DW	16	48	Pb-Free (RoHS)	CU NIPDAU	Level-3-260C-168 HR
UAF42AU-1	OBSOLETE	SOIC	DW	16		TBD	Call TI	Call TI
UAF42AUE4	ACTIVE	SOIC	DW	16	48	Pb-Free (RoHS)	CU NIPDAU	Level-3-260C-168 HR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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